INTEGRATED CIRCUITS

DATA SHEET

PCK857 50-150MHz differential 1:10 SDRAM clock driver

Product data Supersedes data of 2000 Jun 15





50-150 MHz differential 1:10 SDRAM clock driver

PCK857

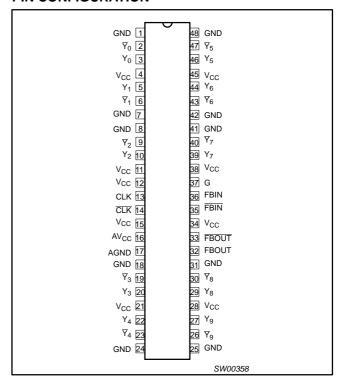
FEATURES

- Optimized for clock distribution in DDR (Double Data Rate) SDRAM applications
- 1-to-10 differential clock distribution
- Very low skew (< 100 ps) and jitter (< 100 ps)
- 3 V AV_{CC} and 2.5 V V_{CC}
- SSTL_2 interface clock inputs and outputs
- CMOS control signal input
- Test mode enables buffers while disabling PLL
- Low current power-down mode
- Tolerant of Spread Spectrum input clock
- Full DDR solution provided when used with SSTL16857 and CBT3857

DESCRIPTION

Zero delay buffer to distribute an SSTL differential clock input pair to 10 SSTL_2 differential output pairs. Outputs are slope controlled. External feedback pin for synchronization of the outputs to the input. A CMOS style Enable/Disable pin is provided for low power disable.

PIN CONFIGURATION



ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER	
48-Pin Plastic TSSOP	0 to +85 °C	PCK857DGG	SOT362-1	

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PIN DESCRIPTION

PINS	SYMBOL	I/O	DESCRIPTION		
17	AGND	Ground	Analog ground. AGND provides the ground reference for the analog circuitry.		
16	AV _{CC}	Power	Analog power supply. AV_{CC} provides the power reference for the analog circuitry. In addition, AV_{CC} can be used to bypass the PLL for test purposes. When AV_{CC} is strapped to ground, PLL is bypassed and CLK is buffered directly to the device outputs. During disable (G = 0), the PLL is powered down.		
13, 14	CLK, CLK	ı	Clock input. CLK provides the clock signal to be distributed by the PCK857 clock driver. CLK is used to provide the reference signal to the integrated PLL that generates the clock output signals. CLK must have a fixed frequency and fixed phase for the PLL to obtain phase lock. Once the circuit is powered up and a valid CLK is applied, a stabilization time is required for the PLL to phase lock the feedback signal to its reference signal.		
36, 35	FB _{IN} , FB_{IN}	I Feedback input. FB _{IN} provides the feedback signal to the inte FB _{IN} must be hard-wired to FB _{OUT} to complete the PLL. The PLL synchronizes CLK and FB _{IN} so that there is nominally ze error between CLK and FB _{IN} .			
32, 33	FB _{OUT} , FB _{OUT}	0	Feedback output. FB_{OUT} is dedicated for external feedback. It switches at the same frequency as CLK. When externally wired to FB_{IN} , FB_{OUT} completes the feedback loop of the PLL.		
37	G	I	Output bank enable. G is the output enable for outputs Y and \overline{Y} . When G is low outputs Y are disabled to a high-impedance state. When G is high, all outputs Y are enabled and switch at the same frequency as CLK.		
1, 7, 8, 18, 24, 25, 31, 41, 42, 48	GND	Ground	Ground		
4, 11, 12, 15, 21, 28, 34, 38, 45	V _{CC}	Power	Power supply		
3, 5, 10, 20, 22, 46, 44, 39, 29, 27	Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7, Y8, Y9	0	Clock outputs. These outputs provide low-skew copies of CLK.		
2, 6, 9, 19, 23, 47, 43, 40, 30, 26	<u>Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7, Y8, Y9</u>	0	Clock outputs. These outputs provide low-skew copies of CLK.		

FUNCTION TABLE

	INPUTS			PLL ON/OFF			
G	CLK	CLK	Y	Y	FBOUT	FBOUT	
L	L	Н	Z	Z	Z ¹	Z ¹	OFF
L	Н	L	Z	Z	Z ¹	Z ¹	OFF
Н	L	Н	L	Н	L	Н	ON
Н	Н	L	Н	L	Н	L	ON
X ²	< 20 MHz	< 20 MHz	Z	Z	Z ¹	Z ¹	OFF

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NOTES:

H = HIGH voltage level

L = LOW voltage level Z = HIGH impedance OFF-state

X = don't care

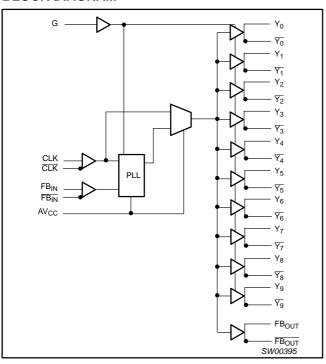
1. Subject to change. May cause conflict with FBIN pins.

2. Additional feature that senses when the clock input is less than 20 MHz and places the part in sleep mode.

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BLOCK DIAGRAM



DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

0)/MD01	DADAM		TEGT CONDITIONS		LIMITS			
SYMBOL	PARAMI	EIEK	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V _{IK}	Input voltage	All input pins	V _{CC} = 2.3 V; I _I = -18 mA			-1.2	V	
			V _{CC} = min to max; I _{OH} = -1 mA	V _{CC} -0.1			.,	
V _{OH}	HIGH-level output	voitage	V _{CC} = 2.3 V; I _{OH} = -12 mA	1.7			V	
	LOW level entert		V _{CC} = min to max; I _{OL} = 1 mA			0.1	٧	
V_{OL}	LOW-level output	voitage	V _{CC} = 2.3 V; I _{OL} = 12 mA			0.6		
I _{OH}	HIGH-level output	current	V _{CC} = 2.3 V; V _O = 1 V	-18	-32		mA	
I _{OL}	LOW-level output current		V _{CC} = 2.3 V; V _O = 1.2 V	26	35		mA	
	I _I Input current G CLK, FB _{IN}		$V_{CC} = 2.7 \text{ V}; V_I = 0 \text{ V to } 2.7 \text{ V}$			±10	^	
Ц			$V_{CC} = 2.7 \text{ V}; V_I = 0 \text{ V to } 2.7 \text{ V}$			±10	μΑ	
l _{OZ}	HIGH-impedance	output current	$V_{CC} = 2.7 \text{ V}; V_O = V_{CC} \text{ or GND}$			±10	μΑ	
Voc	Output crossing po	oint voltage		(V _{CC} /2)-0.1	V _{CC} /2	(V _{CC} /2)+0.1	V	
I _{CCZ}	Supply current, dis	sabled	AV_{CC} and V_{CC} = max, G = L or no input CLK signal		500	800	μА	
I _{CC}	Supply current on AV _{CC}		V_{CC} = 2.7 V, All outputs switching environment; f_O = 167 MHz, 16 pF in 60 Ω See Figure 3		235	330	mA	
Alcc	Supply current on	AV _{CC}	AV _{CC} = 3.6 V; f _O = 167 MHz		9	12	mA	
C _I	Input capacitance		$V_{CC} = 2.5 \text{ V; } V_{I} = V_{CC} \text{ or GND}$		2		pF	
Co	Output capacitano	e	$V_{CC} = 2.5 \text{ V}; V_O = V_{CC} \text{ or GND}$		3		pF	

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ABSOLUTE MAXIMUM RATINGS1,2

SYMBOL	PARAMETER	CONDITION	LIM	IITS	UNIT
STWIBOL	PARAMETER	CONDITION	MIN	MAX	UNIT
V _{CC} /AV _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage	Note 2	-0.5	V _{DDQ} + 0.5	V
V _O	Output voltage	Note 2	-0.5	V _{DDQ} + 0.5	V
I _{IK}	Input diode current	$V_I < O \text{ or } V_I > V_{CC}$		± 50	mA
I _{OK}	Output diode current	$V_O < O \text{ or } V_O > V_{CC}$		± 50	mA
Io	I _O Output source or sink current			± 50	mA
T _{stg}	T _{stg} Storage temperature range		-65	+150	°C
θЈА	Package thermal impedance	Note 3		89	°C/W

NOTES

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 3. The package thermal impedance is calculated in accordance with JESD51.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS		LIMITS		UNIT	
STWIBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT	
V _{CC}	Supply voltage		2.3	2.5	2.7	V	
AV _{CC}	Analog supply voltage		3.0	3.3	3.6	V	
V_{IL}	G input				0.3 XV _{CC}	V	
V _{IH}	G input		0.7 XV _{CC}			V	
VI	CLK, FB _{IN}		-0.3		V _{CC} + 0.3	V	
loh	HIGH-level output current				-12	mA	
I _{OL}	LOW-level output current				12	mA	

timing requirements over recommended ranges or supply voltage and operating free-air temperature

	PARAMETER	CONDITIONS	MIN	MAX	UNIT
f _C	Clock frequency		66	167	MHz
	Input clock duty cycle		40%	60%	
	Stabilization time ¹			100	μS

NOTE:

Time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. For phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at CLK. Until phase lock is obtained, the specifications for propagation delay, skew, and jitter parameters given in the switching characteristics are not applicable. This parameter does not apply for input modulation under SSC application.

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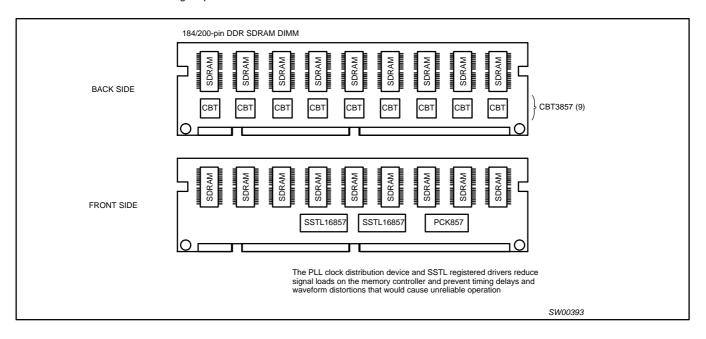
AC CHARACTERISTICS

GND = 0 V; t_r = t_f \leq 2.5 ns; C_L = 50 pF; R_L = 1 k Ω

CVMDOL	DADAMETED	MANEEODM	CONDITION		LIMITS		LINIT
SYMBOL	PARAMETER	WAVEFORM	CONDITION	MIN	TYP	MAX	UNIT
t _{PLH} 1	Low to high propagation	Figure 4	CLK to any output	1.5	3.5	6	ns
t _{PHL} 1	High to low propagation	Figure 4	CLK to any output	1.5	3.5	6	ns
f _{PHASERROR}	Phase error			-150	0	150	ps
f _{SK}	Output clock skew	Figure 1				100	ps
fdif _{SK}	Differential clock skew					100	ps
f _{SL}	Output clock skew rate			1	1.5		V/ns
Jitter _{pp}	Peak-to-Peak jitter (long term)			-100		100	ps
Jitter _{cc}	Cycle-to-cycle jitter (short term)	Figure 3		> -100		< 100	ps
f _{DC}	C Duty cycle			45		55	%
C _{in}	Input capacitance			2.5		4	pF
t _r , t _f	Output rise and fall times		20%-80%	650	800	950	ps

NOTE:

^{1.} Refers to transition of reinverting output.



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AC WAVEFORMS

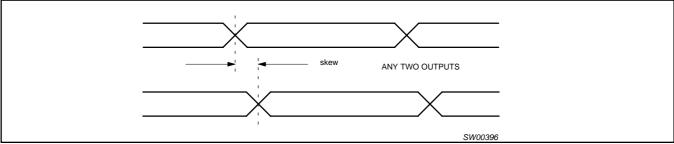


Figure 1. Skew between any two outputs.

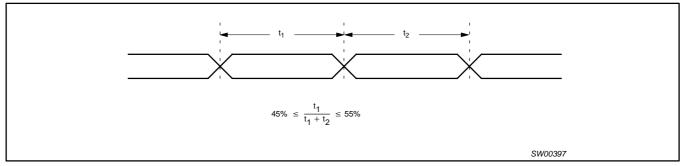


Figure 2. Duty cycle limits and measurement

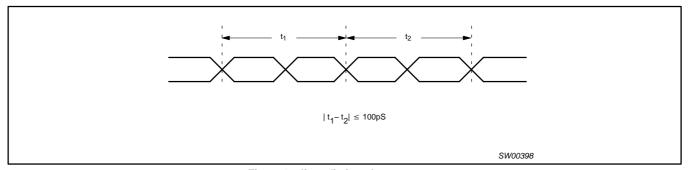


Figure 3. Jitter limit and measurement

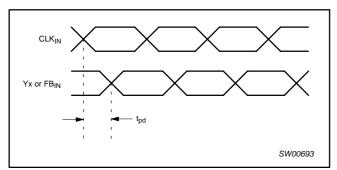
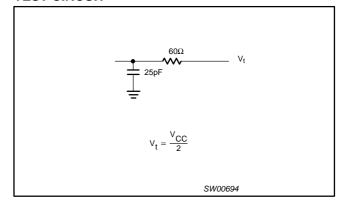


Figure 4. Propagation delay time; t_{PLH}, t_{PHL}

TEST CIRCUIT

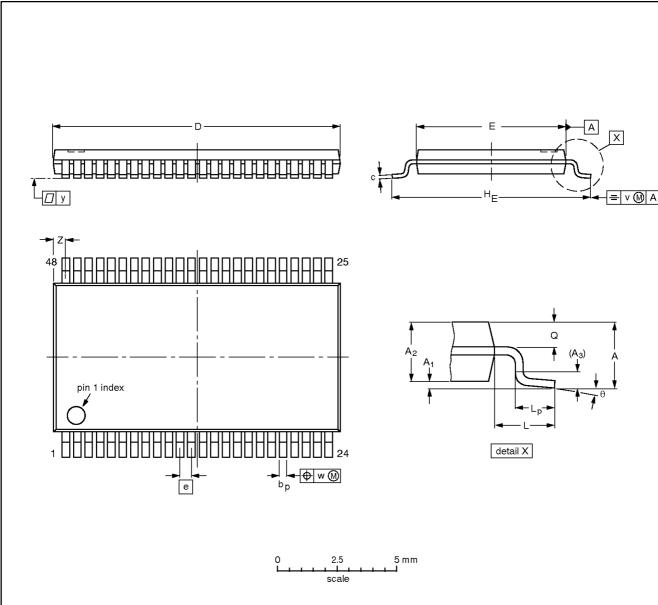


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TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1 mm

SOT362-1



DIMENSIONS (mm are the original dimensions).

UNIT	A max.	A ₁	A ₂	A ₃	bp	O	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	>	w	у	z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT362-1		MO-153				-95-02-10 99-12-27	

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REVISION HISTORY

Rev	Date	Description
_3	20030731	Product data (9397 750 11764); ECN 853-2199 30051 of 18 June 2003; supersedes data of 2000 June 15 (9397 750 07193).
		Modifications:
		 Corrections and minor changes to existing product specifications.
_2	20000715	Product data (9397 750 07193); ECN 853-2199 23880 of 2000 June 15.

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Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definitions
ı	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

^[1] Please consult the most recently issued data sheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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